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INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)		Docket Number (Optional) SETI-0004	Application Number
		Applicant(s) Gaska et al.	
		Filing Date	Group Art Unit
*EXAMINER INITIAL	OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)		
<i>J. E. F.</i>	"Temperature Effect on the Quality of AlN Thin Films," M. P. Thompson et al., MRS Internet J. Nitride Semicond. Res. 4S1, G3.7 (1999).		
<i>J. E. F.</i>	"High Rate and Selective Etching of GaN, AlaN, and AlN Using an Inductively Coupled Plasma," S. A. Smith et al., Applied Physics Letters, Vol. 71, No. 25, December 22, 1997, pp. 3631-3633.		
<i>J. E. F.</i>	"Reactive Sputter Deposition of Highly Oriented AlN Films at Room Temperature," G.F. Iriarte et al., J. Mater. Res., Vol. 17, No. 6, June 2002, pp. 1469-1475.		
<i>J. E. F.</i>	"PVT Growth of Bulk AlN Crystals With Low Oxygen Contamination," M. Bickermann et al., Phys. Stat. Sol. (a), Vol. 195, No. 1, 3-10 (2003), pp. 1 - 4.		
<i>J. E. F.</i>	"Introduction to Solid-State Lighting," Zukauskas et al., pp. 61-69. (2002).		
EXAMINER <i>J. E. F.</i>	DATE CONSIDERED		<i>5/15/04</i>

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